

EGF1A, EGF1B, EGF1C, EGF1D

Vishay General Semiconductor

Surface Mount Glass Passivated Ultrafast Rectifier

SUPERECTIFIER®



DO-214BA (GF1)

1.0 A

50 V, 100 V, 150 V, 200 V

30 A

50 ns

1.0 V

175 °C

DO-214BA (GF1)

Single die

PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

 I_{FSM}

t_{rr}

 V_{F}

T_J max.

Package

Diode variations

FEATURES

- Superectifier structure for high reliability condition
- Cavity-free glass-passivated junction
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low switching losses, high efficiency
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- AEC-Q101 gualified
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214BA, molded epoxy over glass body Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT	
Device marking code		EA	EB	EC	ED		
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	V	
Maximum RMS voltage	V _{RMS}	35	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	50	100	150	200	V	
Maximum average forward rectified current at $T_L = 125$ °C	I _{F(AV)}	1.0				А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30			А		
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175			°C		

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RoHS COMPLIANT

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT
Maximum instantaneous forward voltage	1.0 A		V _F ⁽¹⁾ 1.0			V		
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C	I _R ⁽¹⁾	5.0			μA	
		T _A = 125 °C	'R \ '	50				
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	50			ns	
Typical junction capacitance	4.0 V, 1 MHz		CJ	15			pF	

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT	
Typical thermal registerion	R _{0JA} ⁽¹⁾	85				°C/W	
Typical thermal resistance	R _{0JL} ⁽¹⁾	30					

Note

(1) Thermal resistance from junction to ambient and from junction to lead, PCB mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
EGF1D-E3/67A	0.104	67A	1500	7" diameter plastic tape and reel			
EGF1D-E3/5CA	0.104	5CA	6500	13" diameter plastic tape and reel			
EGF1DHE3/67A (1)	0.104	67A	1500	7" diameter plastic tape and reel			
EGF1DHE3/5CA ⁽¹⁾	0.104	5CA	6500	13" diameter plastic tape and reel			

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise specified)

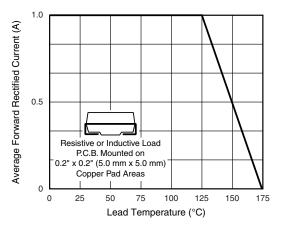


Fig. 1 - Maximum Forward Current Derating Curve

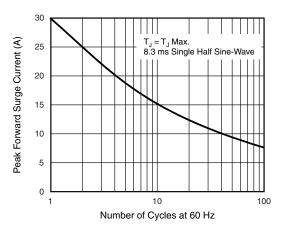


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

Revision: 11-Dec-13

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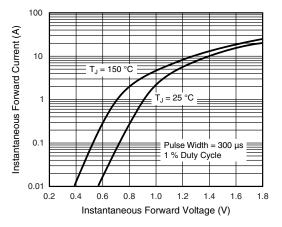


Fig. 3 - Typical Instantaneous Forward Characteristics

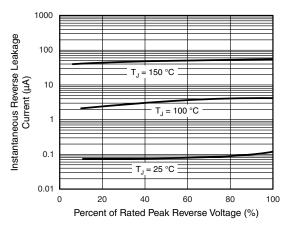


Fig. 4 - Typical Reverse Leakage Characteristics

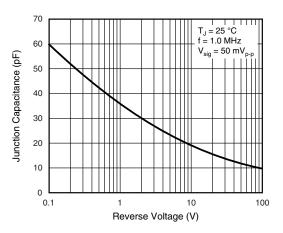


Fig. 5 - Typical Junction Capacitance

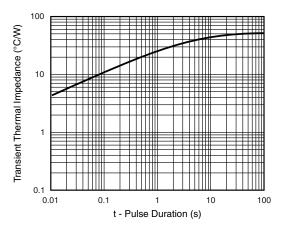
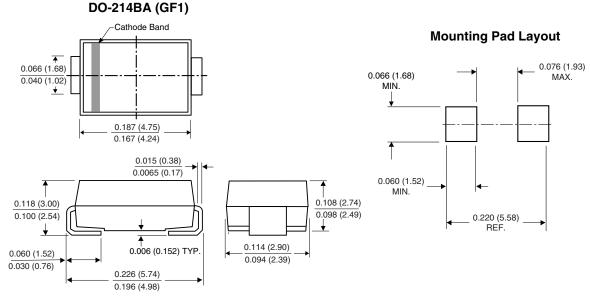


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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